

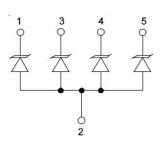
Description

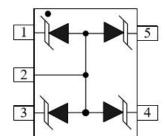
The SMF series TVS arrays are designed to protect sensitive electronics from damage or latch-up due to ESD and other voltage-induced transient events. They are designed for use in applications where board space is at a premium. Each device will protect up to four lines. They are unidirectional devices and may be used on lines where the signal polarities are above ground. TVS diodes are solid-state devices designed specifically for transient suppression. They feature large cross-sectional area junctions for conducting high transient currents. They offer desirable characteristics for board level protection including fast response time, low operating and clamping voltage, and no device degradation. The SMF series devices may be used to meet the immunity requirements of IEC 61000-4-2, level 4.

Features

- Low leakage current (<1µA)
- Working voltage: 5V
- Low clamping voltage
- Protects four I/O lines
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±30kV
 Contact discharge: ±30kV
 - IEC61000-4-5 (Lightning) 8A (8/20µs)
- RoHS Compliant

Dimensions & Symbol (Unit: mm Max)





Circuit Diagram

Pin Schematic

Mechanical Characteristics

- Package: SOT-353
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

- Cellular Handsets and Accessories
- Notebooks and Handhelds
- Personal Digital Assistants
- Portable Instrumentation
- Digital Cameras
- Peripherals

Marking information



Dot denotes Pin1

Details marking code reference customer approval list

Ordering Information

Part Number	Packaging	Reel Size
SMF05	3000/Tape & Reel	7 inch



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	100	W
Peak Pulse Current (8/20µs)	Ірр	8	А
ESD per IEC 61000-4-2 (Air)		±30	
ESD per IEC 61000-4-2 (Contact)	VESD	±30	kV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

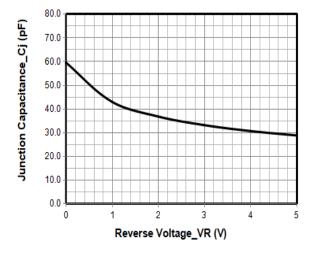
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Мах	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Reverse Breakdown Voltage	Vbr	6		8.5	V	IT = 1mA
Reverse Leakage Current	I _R			0.2	μA	VRWM = 5V, any I/O pin to ground
Clamping Voltage	Vc			8	V	IPP = 1A (8 x 20µs pulse), any I/O pin to ground
Clamping Voltage	Vc			12	V	IPP = 8A (8 x 20µs pulse), any I/O pin to ground
Junction Capacitance	Сл		60		pF	VR = 0V, f = 1MHz, any I/O pin to ground

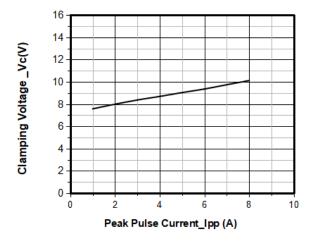
Note 1: I/O pins are Pin 1, 3, 4, 5

Incorporated

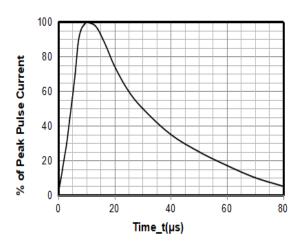
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



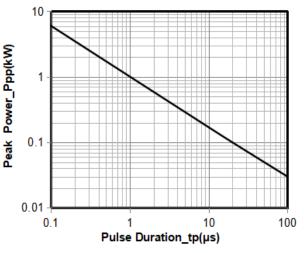
Junction Capacitance vs. Reverse Voltage



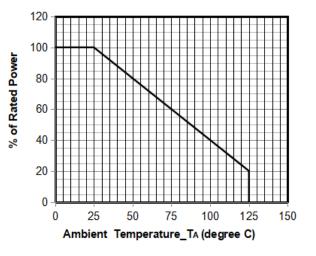
Clamping Voltage vs. Peak Pulse Current



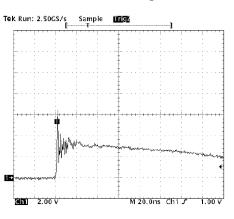
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



Power Derating Curve



Note: Data is taken with a 10x attenuator

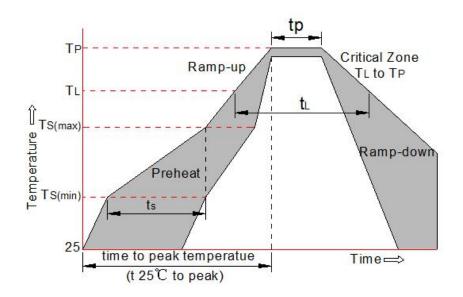
ESD Clamping Voltage

8 kV Contact per IEC61000-4-2



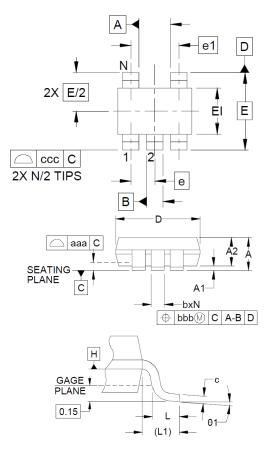
Soldering parameters

Reflow Condition		Pb-Free assembly (see FIG.2)	
	-Temperature Min (T _{s(min)})	+150℃	
Pre Heat	-Temperature Max(T _{s(max)})	+200 ℃	
	-Time (Min to Max) (ts)	60-180 secs.	
Average ramp up rate (Liquid us Temp (T _L) to peak)		3℃/sec. Max	
T _{s(max)} to T _L - Ramp-up Rate		3℃/sec. Max	
Reflow	-Temperature(T _L) (Liquid us)	+217℃	
	-Temperature(t∟)	60-150 secs.	
Peak Temp (T _p)		+260(+0/-5) ℃	
Time within 5 $^\circ \!\!\!\!\!^{\rm C}$ of actual Peak Temp (t_p)		30 secs. Max	
Ramp-down Rate		6℃/sec. Max	
Time 25°C to Peak Temp (T _P)		8 min. Max	
Do not exceed		+260 ℃	



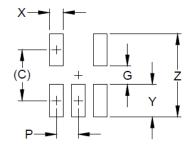


Package mechanical data



	DIMENSIONS					
DIM	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
Α	-	-	.043	-	-	1.10
A1	.000	-	.004	0.00	-	0.10
A2	.028	.035	.039	0.70	0.90	1.00
b	.006	-	.012	0.15	-	0.30
С	.003	-	.009	0.08	-	0.22
D	.075	.079	.083	1.90	2.00	2.10
E1	.045	.049	.053	1.15	1.25	1.35
E	.083 BSC			2.10 BSC		
е	.026 BSC			0.65 BSC		
e1		.051		1.30 BSC		
L	.010	.014	. <mark>018</mark>	0.26	0.36	0.46
L1	(.017)			(0.42)		
Ν	5			5		
0 1	0°	-	8°	0°	-	8°
aaa	.004				0.10	
bbb	.004			0.10		
CCC	.012				0.30	

Suggested Land Pattern



SYM	DIMENSIONS				
	MILLIMETERS	INCHES			
С	1.85	0.073			
G	1.00	0.039			
Р	0.65	0.026			
Х	0.40	0.016			
Y	0.85	0.033			
Z	2.70	0.106			

Contact information

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